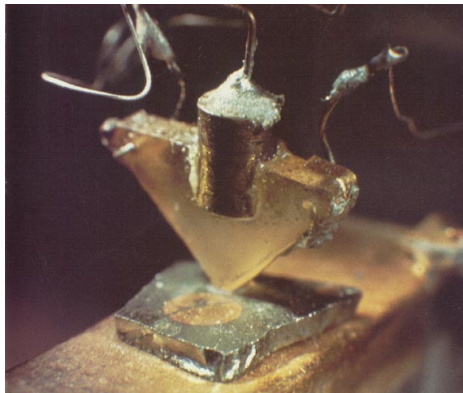
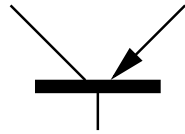


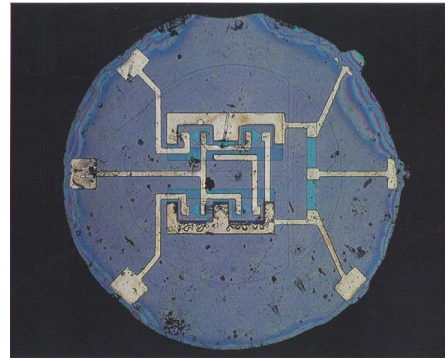
1947 Point Contact transistor



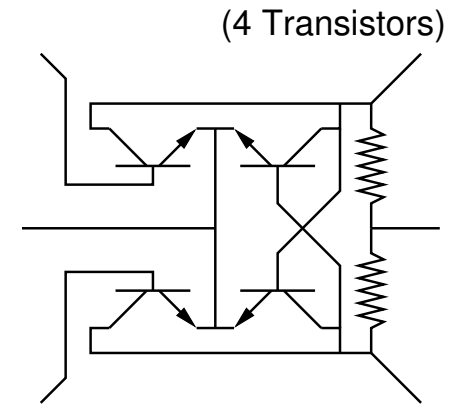
Source: Bell Labs



1961 Fairchild Bipolar RTL RS Flip-Flop

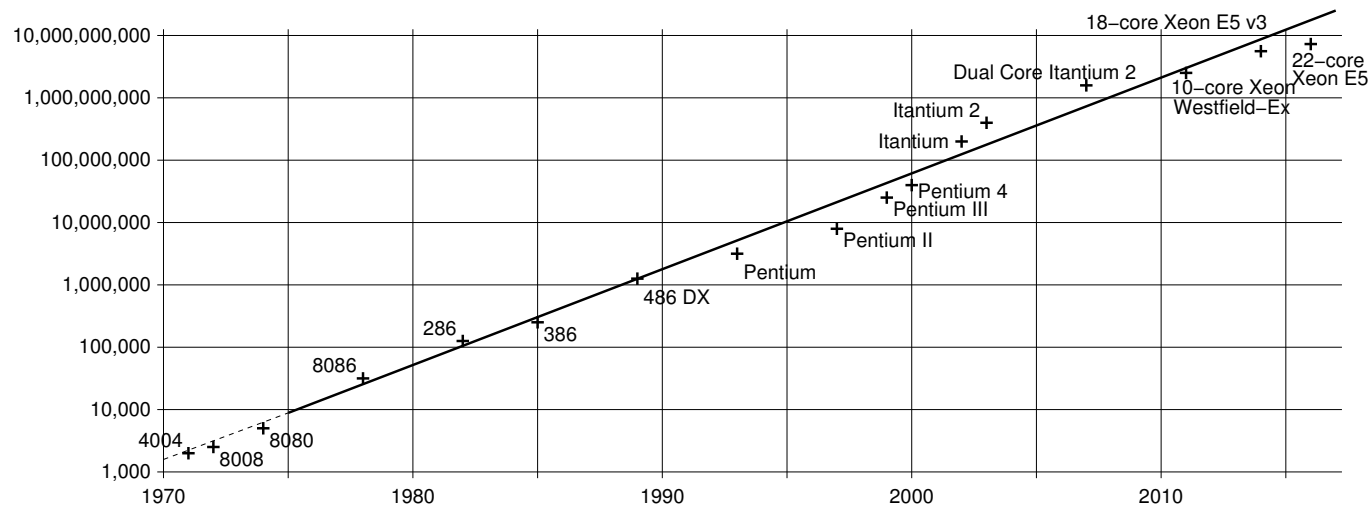


Source: Fairchild



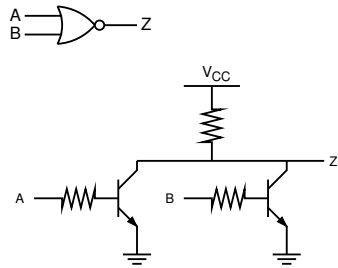
Moore's Law (1965) Number of transistor has doubled every year and will continue to do so until 1975

Moore's Law (1975) Number of transistors will double every two years

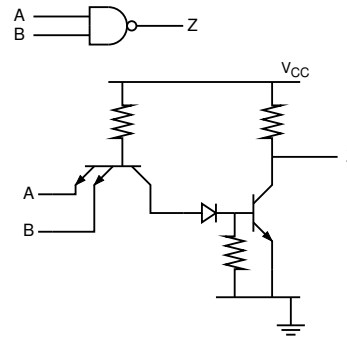


Self-fulfilling Prophecy

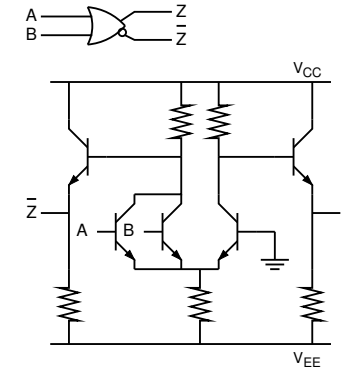
RTL NOR Gate



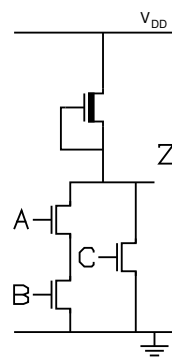
TTL NAND Gate



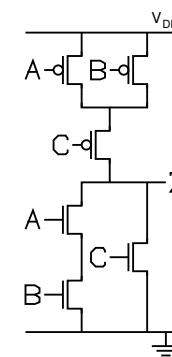
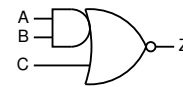
ECL OR/NOR Gate



NMOS Compound Gate



CMOS Compound Gate



- Bipolar Transistors with Resistors - MSI/LSI

RTL - NOR

TTL - NAND

ECL - OR/NOR

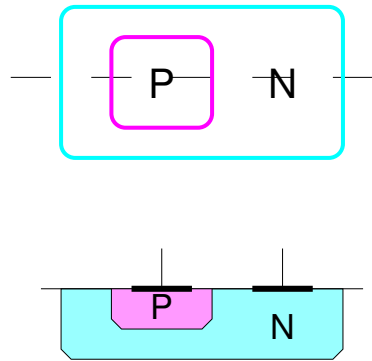
- MOS Transistors (no resistors) - VLSI

NMOS

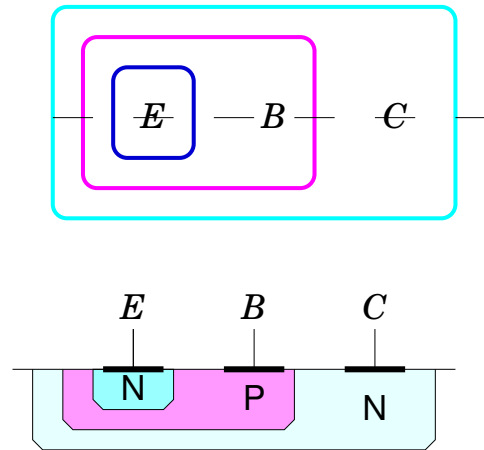
CMOS - No static power!

*Both allow construction of NOR, NAND & Compound gate (always inverting)*

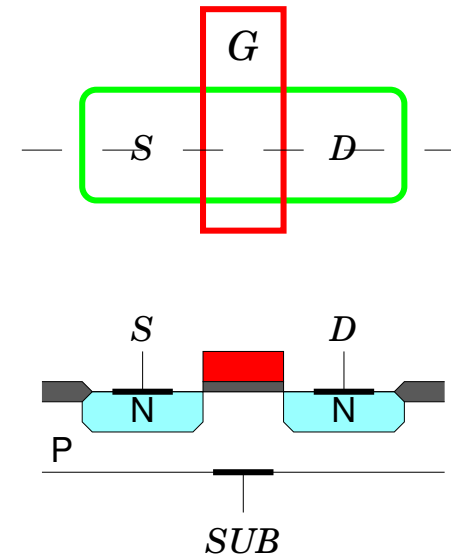
Diode



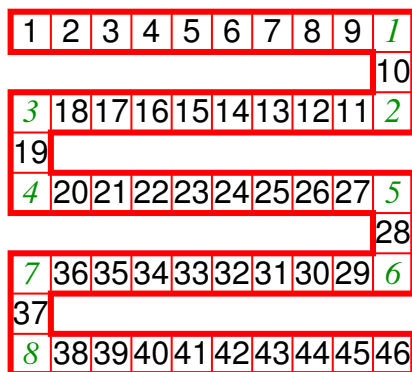
NPN Transistor



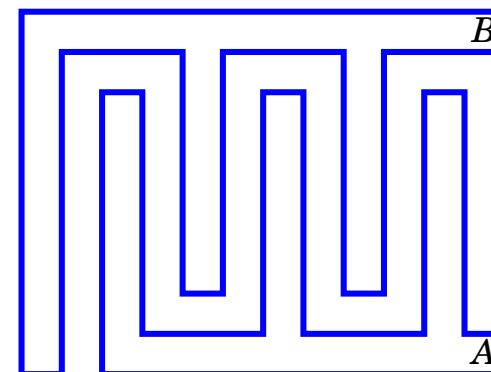
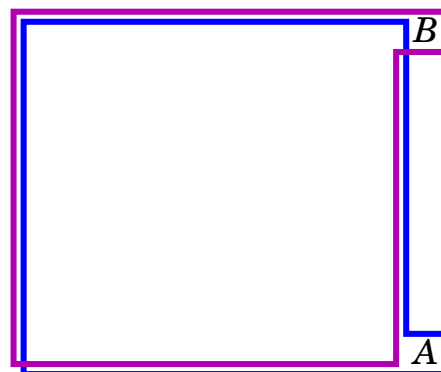
NMOS Enhancement transistor  
NMOS Process



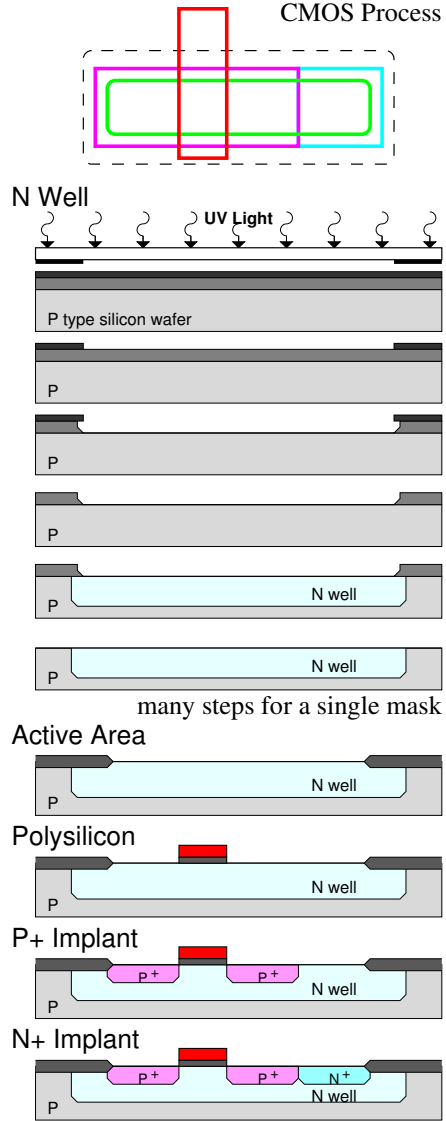
Resistor



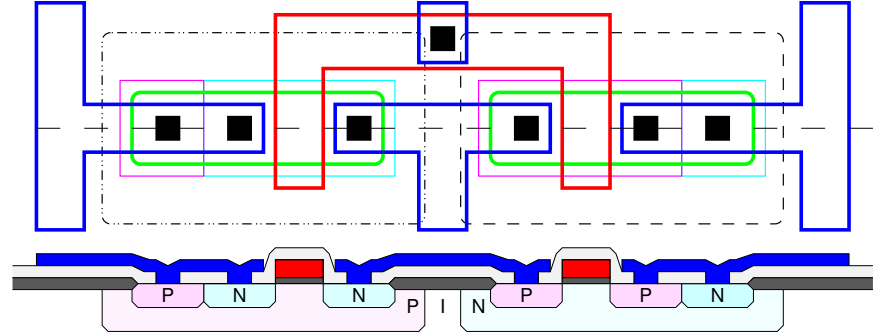
Capacitors



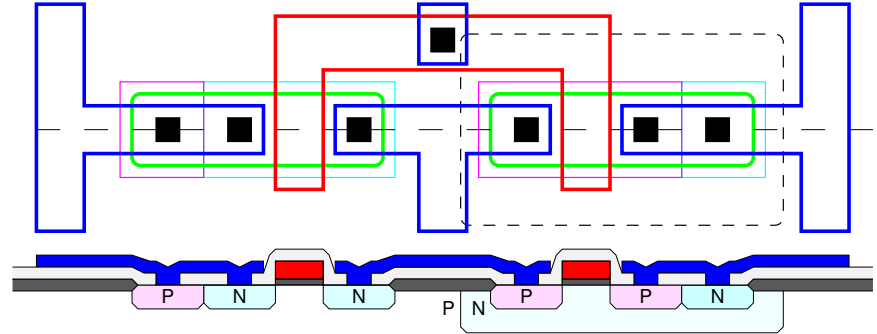
PMOS Enhancement transistor CMOS Process



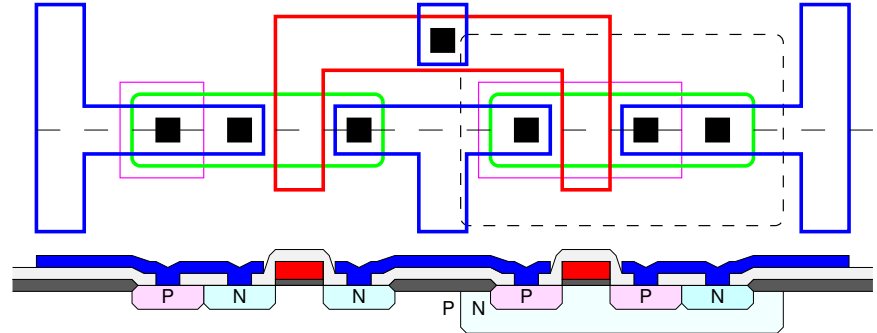
CMOS Inverter Twin Tub CMOS Process



CMOS Inverter N-Well CMOS Process (with explicit N+ implant mask)

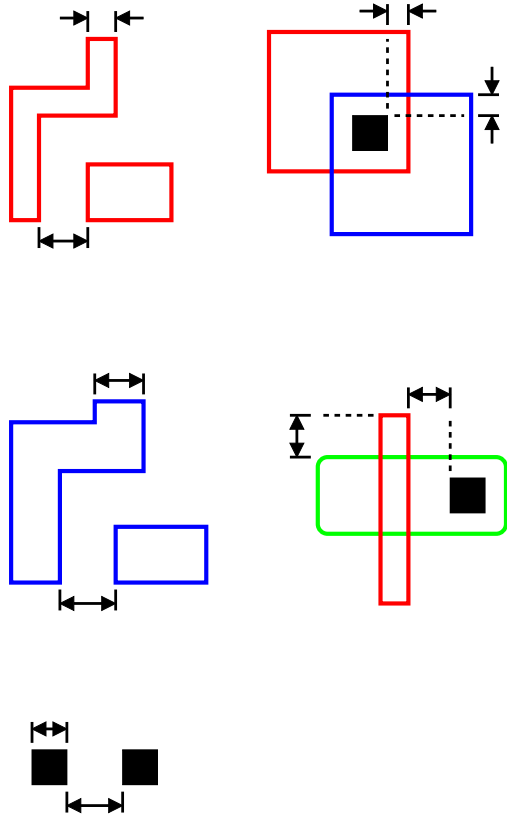


CMOS Inverter N-Well CMOS Process (without explicit N+ implant mask)

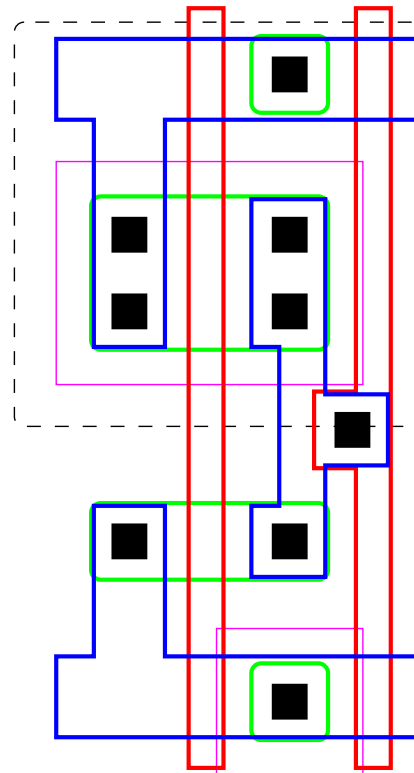


Features may be determined by a number of masks  
 e.g. NMOS source drain: ActiveArea AND NOT(NWell OR Poly OR PImplant)

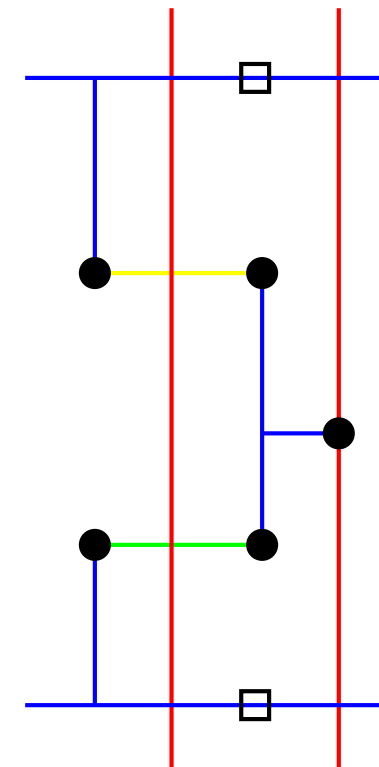
Design Rules – width, separation, overlap



Optimised Mask Layout

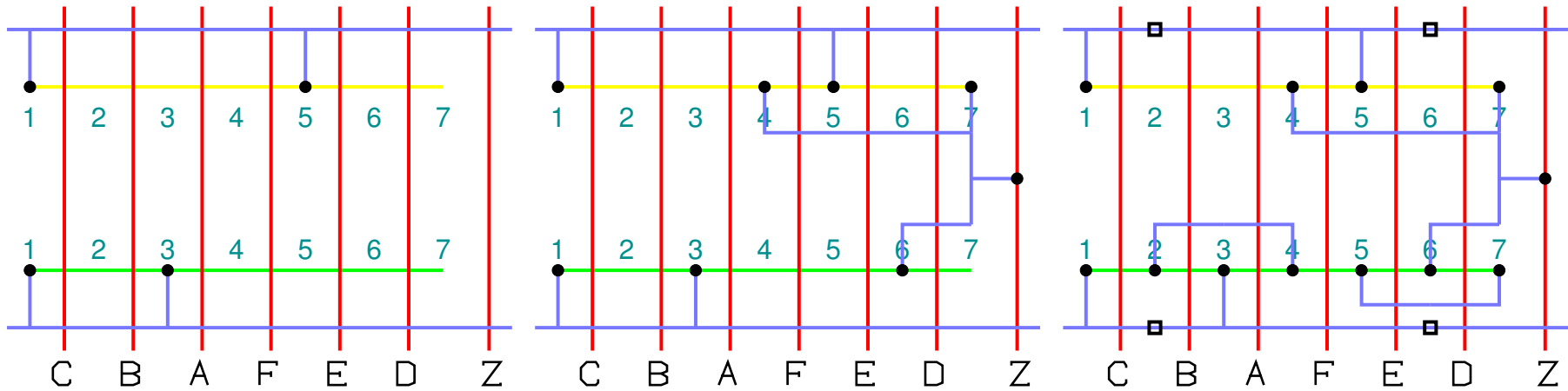
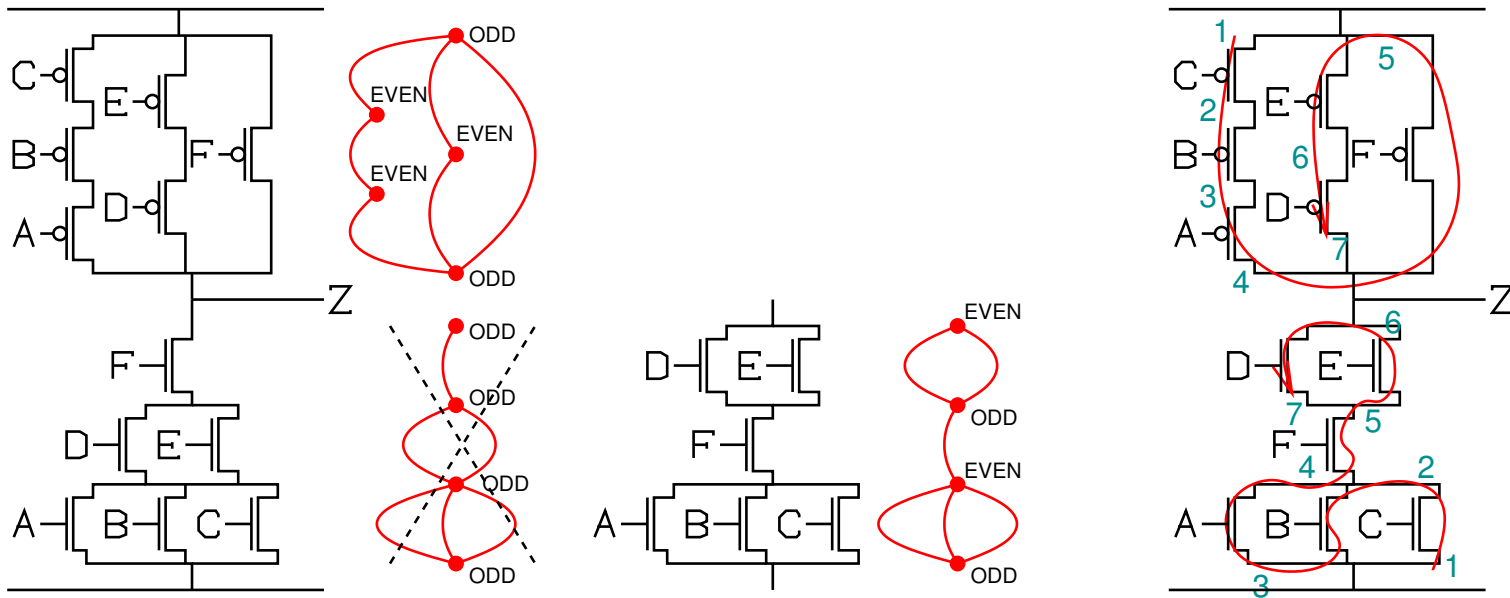


Equivalent Stick Diagram



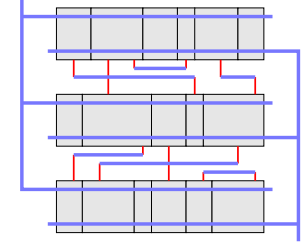
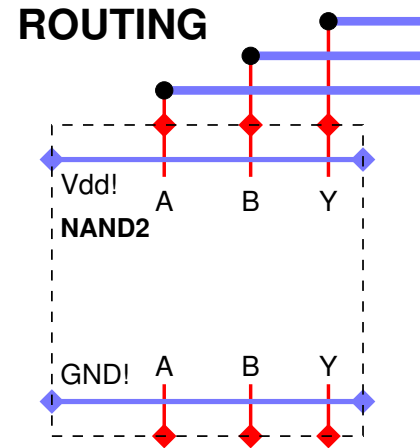
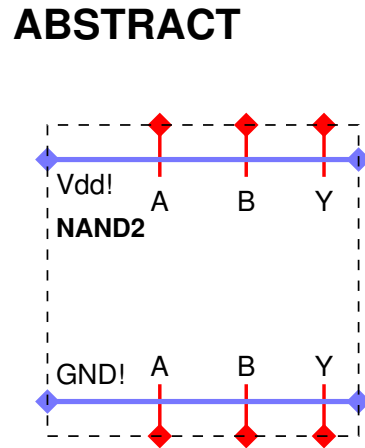
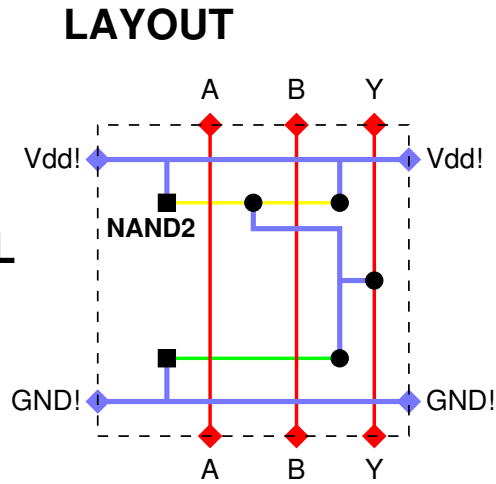
- Metal
- Polysilicon
- N+
- P+
- Contact
- Tap
- Combined contact & tap

# Investigation of Euler paths leads to more efficient layout\*

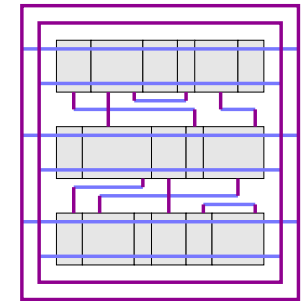
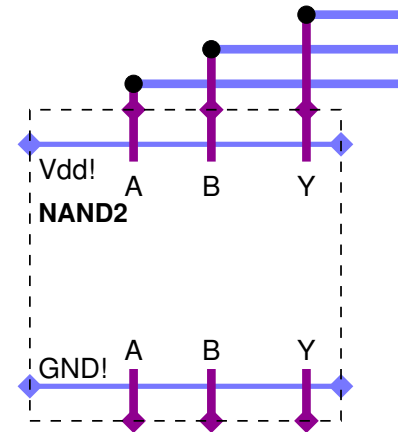
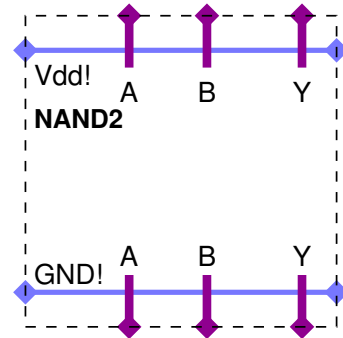
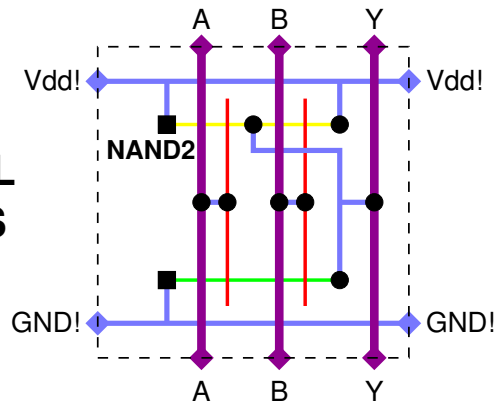


\*not all gates will support a common Euler path for both PMOS and NMOS

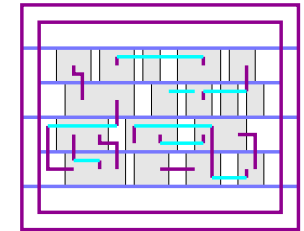
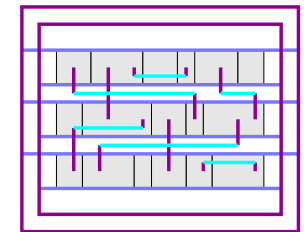
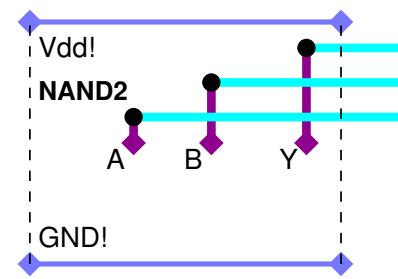
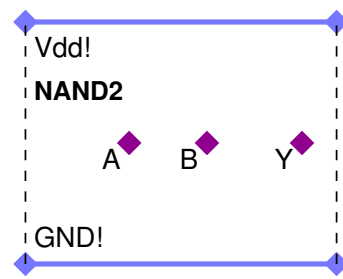
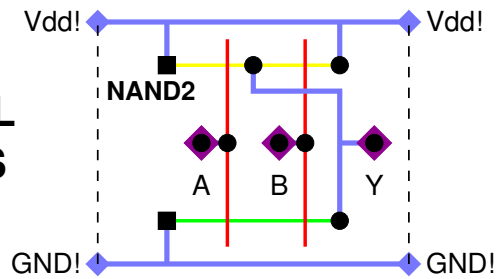
### 1 METAL LAYER

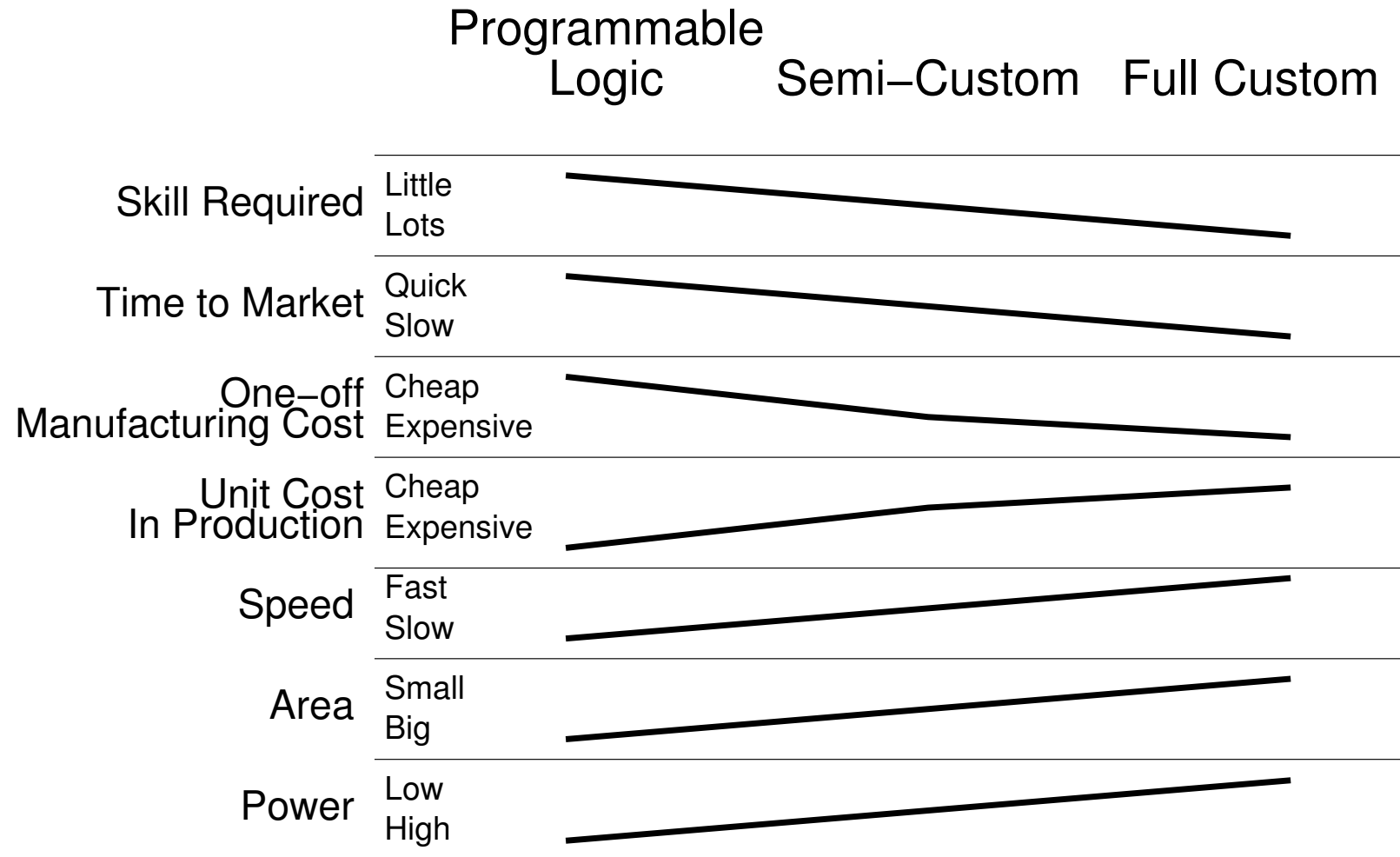


### 2 METAL LAYERS



### 3 METAL LAYERS





All design styles need full custom designers

A large ASIC (especially SoC) may mix Semi-Custom and Full Custom